

30V N-Channel Enhancement Mode MOSFET – ESD Protected

Voltage 30 V Current 1.6A

Features

- RDS(ON), VGS@4,5V, ID@1.6A<200mΩ
- RDS(ON), VGS@2.5V, ID@1.1A<270mΩ
- RDS(ON), VGS@1.8V, ID@0.2A<570mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

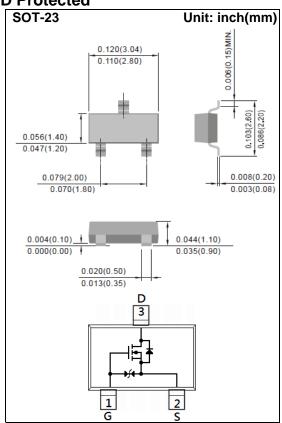
Mechanical Data

• Case: SOT-23 Package

Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A32



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	1.6	Α
Pulsed Drain Current ^(Note 4)		I _{DM}	6.4	Α
Power Dissipation	T _a =25°C		1.25	W
	Derate above 25°C	P□	10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient ^(Note 3)		R _{θJA}	100	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =250uA		30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.5	0.78	1.3	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =1.6A	-	145	200	mΩ	
		V _{GS} =2.5V, I _D =1.1A	-	185	270		
		V _{GS} =1.8V, I _D =0.2A	-	330	570		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	1.4	<u>+</u> 10	uA	
Dynamic ^(Note 5)							
Total Gate Charge	Qg	\/ 45\/ 4.6A	-	1.5	-	nC	
Gate-Source Charge	Q_gs	V _{DS} =15V, I _D =1.6A,	-	0.3	-		
Gate-Drain Charge	Q_gd	VGS=4.5V(1000 1,2)	-	0.3	-		
Input Capacitance	Ciss	\/ 45\/ \/ 0\/	-	93	-	pF	
Output Capacitance	Coss	V _{DS} =15V, V _{GS} =0V,	-	19	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	6	-		
Turn-On Delay Time	td _(on)	45)/ 4 6 4	-	6.4	-		
Turn-On Rise Time	tr	V _{DD} =15V, I _D =1.6A,	-	33	-		
Turn-Off Delay Time	td _(off)	$V_{GS}=4.5V$, $R_{G}=6\Omega^{(Note 1,2)}$	-	37	-	ns	
Turn-Off Fall Time	tf	KG=012(Note 1,2)	-	32	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		_	_	1.0	А	
Diode Forward Current	15			_	1.0		
Diode Forward Voltage	V _{SD}	Is=1.0A, V _{GS} =0V	-	0.81	1.2	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

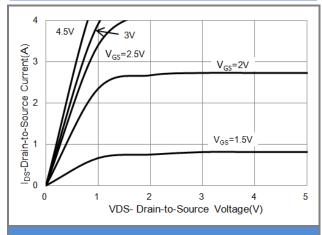


Fig.1 On-Region Characteristics

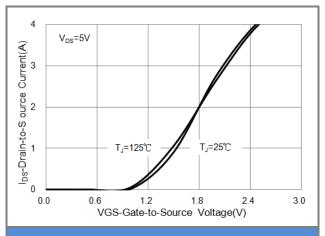


Fig.2 Transfer Characteristics

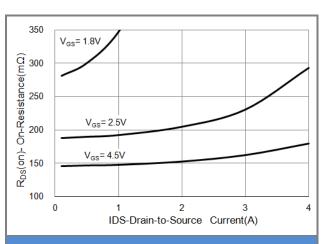


Fig.3 On-Resistance vs. Drain Current

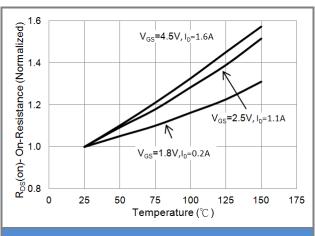


Fig.4 On-Resistance vs. Junction temperature

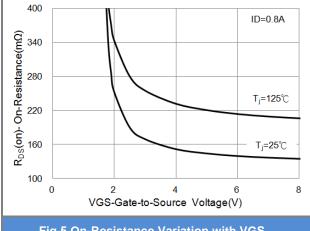
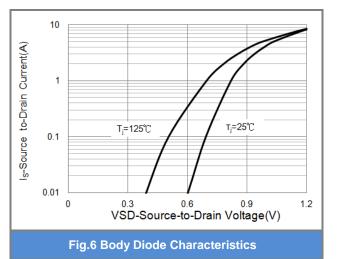


Fig.5 On-Resistance Variation with VGS.





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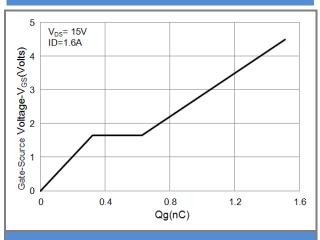


Fig.7 Gate-Charge Characteristics

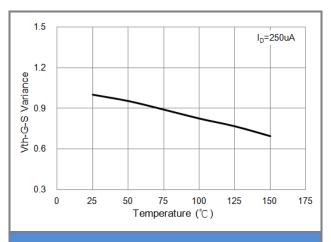


Fig.8 Threshold Voltage Variation with Temperature.

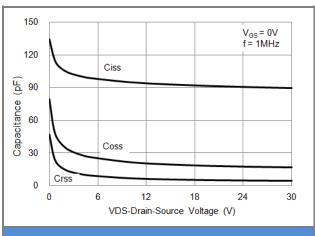


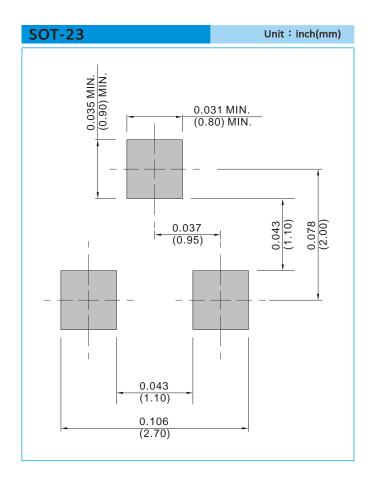
Fig.9 Capacitance vs. Drain-Source Voltage.



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3432	SOT-23	3K pcs / 7" reel	A32	

Mounting Pad Layout





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